

# SN54ABT823, SN74ABT823 9-BIT BUS-INTERFACE FLIP-FLOPS WITH 3-STATE OUTPUTS

SCBS158E – JANUARY 1991 – REVISED MAY 1997

- **State-of-the-Art EPIC-<sup>II</sup>B™ BiCMOS Design Significantly Reduces Power Dissipation**
- **ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)**
- **Latch-Up Performance Exceeds 500 mA Per JEDEC Standard JESD-17**
- **Typical  $V_{OLP}$  (Output Ground Bounce) < 1 V at  $V_{CC} = 5$  V,  $T_A = 25^\circ\text{C}$**
- **High-Impedance State During Power Up and Power Down**
- **High-Drive Outputs (–32-mA  $I_{OH}$ , 64-mA  $I_{OL}$ )**
- **Buffered Control Inputs to Reduce dc Loading Effects**
- **Package Options Include Plastic Small-Outline (DW) and Shrink Small-Outline (DB) Packages, Ceramic Chip Carriers (FK) and Flatpacks (W), and Standard Plastic (NT) and Ceramic (JT) DIPs**

## description

These 9-bit flip-flops feature 3-state outputs designed specifically for driving highly capacitive or relatively low-impedance loads. They are particularly suitable for implementing wider buffer registers, I/O ports, bidirectional bus drivers with parity, and working registers.

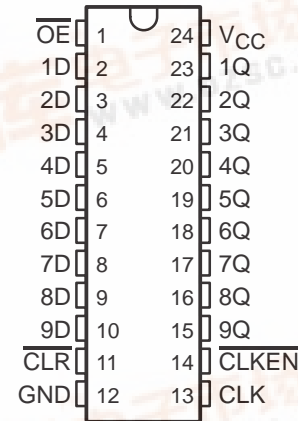
With the clock-enable ( $\overline{\text{CLKEN}}$ ) input low, the nine D-type edge-triggered flip-flops enter data on the low-to-high transitions of the clock. Taking  $\overline{\text{CLKEN}}$  high disables the clock buffer, thus latching the outputs. Taking the clear (CLR) input low causes the nine Q outputs to go low, independently of the clock.

A buffered output-enable ( $\overline{\text{OE}}$ ) input can be used to place the nine outputs in either a normal logic state (high or low logic level) or a high-impedance state. In the high-impedance state, the outputs neither load nor drive the bus lines significantly. The high-impedance state and increased drive provide the capability to drive bus lines without need for interface or pullup components.

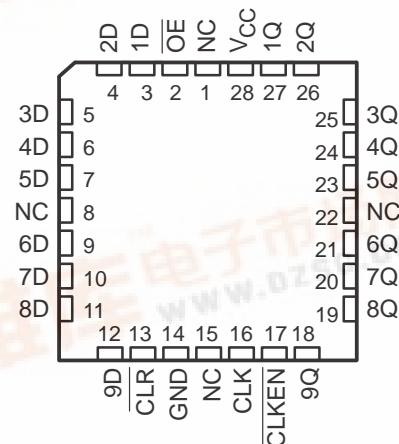
When  $V_{CC}$  is between 0 and 2.1 V, the device is in the high-impedance state during power up or power down. However, to ensure the high-impedance state above 2.1 V,  $\overline{\text{OE}}$  should be tied to  $V_{CC}$  through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54ABT823 is characterized for operation over the full military temperature range of  $-55^\circ\text{C}$  to  $125^\circ\text{C}$ . The SN74ABT823 is characterized for operation from  $-40^\circ\text{C}$  to  $85^\circ\text{C}$ .

SN54ABT823 ... JT OR W PACKAGE  
SN74ABT823 ... DB, DW, OR NT PACKAGE  
(TOP VIEW)



SN54ABT823 ... FK PACKAGE  
(TOP VIEW)



NC – No internal connection

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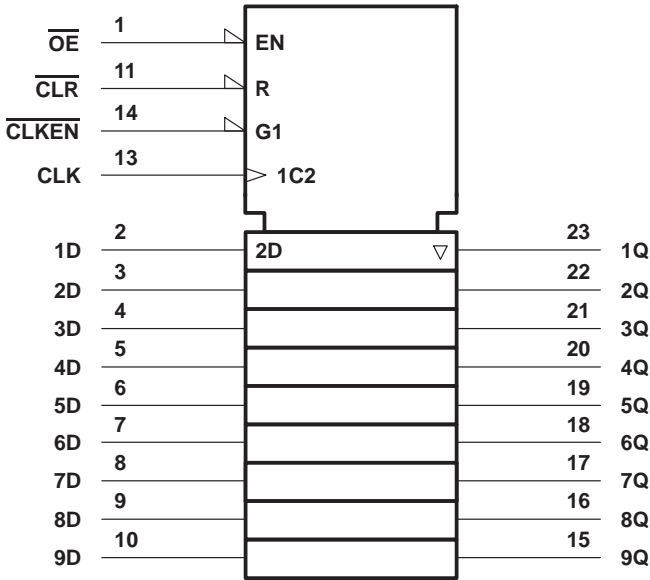
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9-BIT BUS-INTERFACE FLIP-FLOPS  
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FUNCTION TABLE  
(each flip-flop)

INPUTS					OUTPUT Q
$\overline{\text{OE}}$	$\overline{\text{CLR}}$	$\overline{\text{CLKEN}}$	CLK	D	
L	L	X	X	X	L
L	H	L	$\uparrow$	H	H
L	H	L	$\uparrow$	L	L
L	H	H	X	X	$Q_0$
H	X	X	X	X	Z

logic symbol†



† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.  
Pin numbers shown are for the DB, DW, JT, NT, and W packages.



# SN54ABT823, SN74ABT823

## 9-BIT BUS-INTERFACE FLIP-FLOPS

### WITH 3-STATE OUTPUTS

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#### recommended operating conditions (see Note 3)

		SN54ABT823		SN74ABT823		UNIT
		MIN	MAX	MIN	MAX	
V <sub>CC</sub>	Supply voltage	4.5	5.5	4.5	5.5	V
V <sub>IH</sub>	High-level input voltage	2		2		V
V <sub>IL</sub>	Low-level input voltage		0.8		0.8	V
V <sub>I</sub>	Input voltage	0	V <sub>CC</sub>	0	V <sub>CC</sub>	V
I <sub>OH</sub>	High-level output current		–24		–32	mA
I <sub>OL</sub>	Low-level output current		48		64	mA
Δt/Δv	Input transition rise or fall rate		5		5	ns/V
Δt/ΔV <sub>CC</sub>	Power-up ramp rate	200		200		μs/V
T <sub>A</sub>	Operating free-air temperature	–55	125	–40	85	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

#### electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS	T <sub>A</sub> = 25°C			SN54ABT823		SN74ABT823		UNIT
		MIN	TYP†	MAX	MIN	MAX	MIN	MAX	
V <sub>IK</sub>	V <sub>CC</sub> = 4.5 V, I <sub>I</sub> = –18 mA			–1.2		–1.2		–1.2	V
V <sub>OH</sub>	V <sub>CC</sub> = 4.5 V, I <sub>OH</sub> = –3 mA	2.5			2.5		2.5		V
	V <sub>CC</sub> = 5 V, I <sub>OH</sub> = –3 mA	3			3		3		
	V <sub>CC</sub> = 4.5 V	I <sub>OH</sub> = –24 mA	2		2				
		I <sub>OH</sub> = –32 mA	2*				2		
V <sub>OL</sub>	V <sub>CC</sub> = 4.5 V	I <sub>OL</sub> = 48 mA		0.55		0.55			V
		I <sub>OL</sub> = 64 mA		0.55*				0.55	
V <sub>hys</sub>			100						mV
I <sub>I</sub>	V <sub>CC</sub> = 5.5 V, V <sub>I</sub> = V <sub>CC</sub> or GND			±1		±1		±1	μA
I <sub>OZPU</sub> ‡	V <sub>CC</sub> = 0 to 2.1 V, V <sub>O</sub> = 0.5 V to 2.7 V, $\overline{OE} = X$			±50		±50		±50	μA
I <sub>OZPD</sub> ‡	V <sub>CC</sub> = 2.1 V to 0, V <sub>O</sub> = 0.5 V to 2.7 V, $\overline{OE} = X$			±50		±50		±50	μA
I <sub>OZH</sub>	V <sub>CC</sub> = 2.1 V to 5.5 V, V <sub>O</sub> = 2.7 V, $\overline{OE} \geq 2$ V			10§		10§		10§	μA
I <sub>OZL</sub>	V <sub>CC</sub> = 2.1 V to 5.5 V, V <sub>O</sub> = 0.5 V, $\overline{OE} \geq 2$ V			–10§		–10§		–10§	μA
I <sub>off</sub>	V <sub>CC</sub> = 0, V <sub>I</sub> or V <sub>O</sub> ≤ 4.5 V			±100				±100	μA
I <sub>CEX</sub>	V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 5.5 V			50		50		50	μA
I <sub>O</sub> ¶	V <sub>CC</sub> = 5.5 V, V <sub>O</sub> = 2.5 V	–50	–140	–180	–50	–180	–50	–180	mA
I <sub>CC</sub>	V <sub>CC</sub> = 5.5 V, I <sub>O</sub> = 0, V <sub>I</sub> = V <sub>CC</sub> or GND			1	250	250		250	μA
				24	38	38		38	mA
				0.5	250	250		250	μA
ΔI <sub>CC</sub> #	V <sub>CC</sub> = 5.5 V, One input at 3.4 V, Other inputs at V <sub>CC</sub> or GND			1.5		1.5		1.5	mA
C <sub>i</sub>	V <sub>I</sub> = 2.5 V or 0.5 V			4					pF
C <sub>O</sub>	V <sub>O</sub> = 2.5 V or 0.5 V			7					pF

\* On products compliant to MIL-PRF-38535, this parameter does not apply.

† All typical values are at V<sub>CC</sub> = 5 V.

‡ This parameter is characterized, but not production tested.

§ This data sheet limit may vary among suppliers.

¶ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

# This is the increase in supply current for each input that is at the specified TTL voltage level rather than V<sub>CC</sub> or GND.

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## 9-BIT BUS-INTERFACE FLIP-FLOPS

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timing requirements over recommended ranges of supply voltage and operating free-air temperature (unless otherwise noted) (see Figure 1)

			$V_{CC} = 5\text{ V}$ , $T_A = 25^\circ\text{C}$		SN54ABT823		SN74ABT823		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
$f_{\text{clock}}$	Clock frequency		0	125	0	125	0	125	MHz
$t_w$	Pulse duration	$\overline{\text{CLR}}$ low	5.5		5.5		5.5		ns
		CLK high	2.9		2.9		2.9		
		CLK low	3.8		3.8		3.8		
$t_{\text{su}}$	Setup time before CLK $\uparrow$	$\overline{\text{CLR}}$ inactive	2.5		2.5		2.5		ns
		Data	2.1		2.1		2.1		
		CLKEN high	2		2		2		
		CLKEN low	3.3		3.3		3.3		
$t_h$	Hold time after CLK $\uparrow$	Data	1.3		1.3		1.3		ns
		CLKEN high	1		1		1		
		CLKEN low	2		2		2		

switching characteristics over recommended ranges of supply voltage and operating free-air temperature,  $C_L = 50\text{ pF}$  (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5\text{ V}$ , $T_A = 25^\circ\text{C}$			SN54ABT823		SN74ABT823		UNIT
			MIN	TYP	MAX	MIN	MAX	MIN	MAX	
$f_{\text{max}}$			125	200		125		125		MHz
$t_{\text{PLH}}$	CLK	Q	2.1	4.3	5.9	2.1	8.1	2.1	6.8	ns
$t_{\text{PHL}}$			2.2	4.4	6.1	2.2	7	2.2	6.7	
$t_{\text{PHL}}$	$\overline{\text{CLR}}$	Q	2	4.1	6.3	2	7.3	2	7.1	ns
$t_{\text{PZH}}$	$\overline{\text{OE}}$	Q	1	3	4.7 $^\dagger$	1	6.3	1	6 $^\dagger$	ns
$t_{\text{PZL}}$			2.2	4.1	5.6	2.2	6.6	2.2	6.5 $^\dagger$	
$t_{\text{PHZ}}$	$\overline{\text{OE}}$	Q	2.7	4.8	6.5 $^\dagger$	2.7	7.7	2.7	7.5 $^\dagger$	ns
$t_{\text{PLZ}}$			1.9	5	6.4	1.9	7.4	1.9	6.9	

$^\dagger$  This data sheet limit may vary among suppliers.

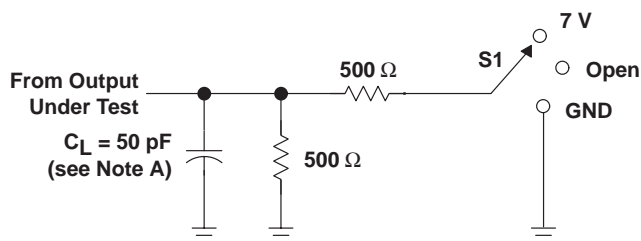
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### WITH 3-STATE OUTPUTS

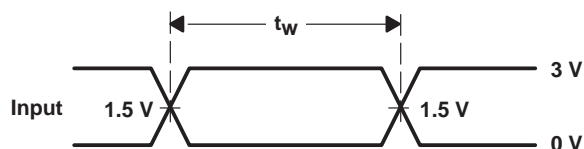
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#### PARAMETER MEASUREMENT INFORMATION

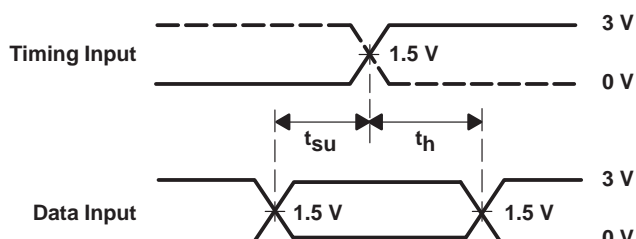


LOAD CIRCUIT

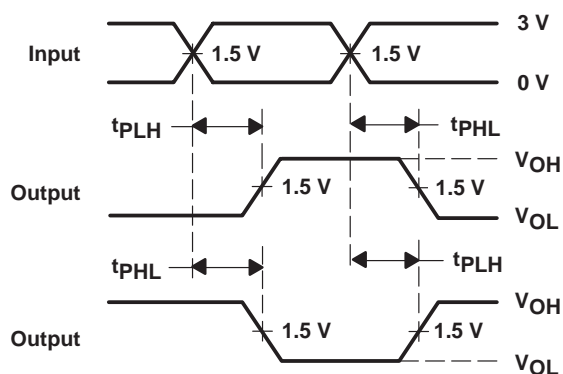
TEST	S1
$t_{PLH}/t_{PHL}$	Open
$t_{PLZ}/t_{PZL}$	7 V
$t_{PHZ}/t_{PZH}$	Open



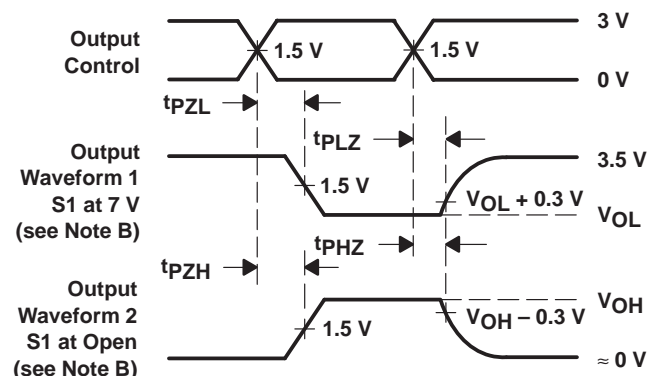
VOLTAGE WAVEFORMS  
PULSE DURATION



VOLTAGE WAVEFORMS  
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS  
PROPAGATION DELAY TIMES  
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS  
ENABLE AND DISABLE TIMES  
LOW- AND HIGH-LEVEL ENABLING

- NOTES: A.  $C_L$  includes probe and jig capacitance.
- B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
- C. All input pulses are supplied by generators having the following characteristics:  $PRR \leq 10 \text{ MHz}$ ,  $Z_O = 50 \Omega$ ,  $t_r \leq 2.5 \text{ ns}$ ,  $t_f \leq 2.5 \text{ ns}$ .
- D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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